

ESD Protection Diode

NSPM2051

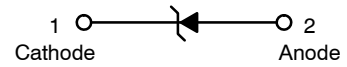
Features

- Protection for the following IEC Standards:
 IEC61000-4-2 Level 4: ± 30 kV Contact Discharge
 IEC61000-4-5 (Lightning) 100 A (8/20 μ s)
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
IEC 61000-4-2 (ESD) Contact Air		± 30 ± 30	kV
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-65 to +150	$^{\circ}$ C
Maximum Peak Pulse Current 8/20 μ s @ $T_A = 25^{\circ}$ C	I_{PP}	100	A

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



UDFN2
CASE 517CZ

MARKING DIAGRAM



M2 = Specific Device Code
 M = Date Code

ORDERING INFORMATION

Device	Package	Shipping [†]
NSPM2051MUT5G	UDFN2 (Pb-Free/ Halide Free)	8000 / Tape & Reel

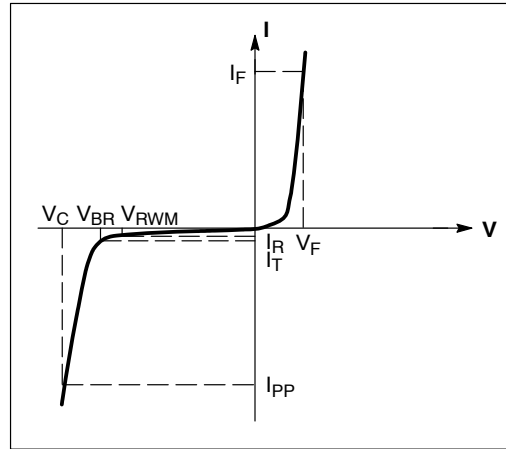
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

ELECTRICAL CHARACTERISTICS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
V_{RWM}	Working Peak Reverse Voltage
I_R	Maximum Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current

*See Application Note [AND8308/D](#) for detailed explanations of datasheet parameters.



Uni-Directional

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse Working Voltage	V_{RWM}				5.0	V
Breakdown Voltage (Note 1)	V_{BR}	$I_T = 1\text{ mA}$	5.1		7.0	V
Reverse Leakage Current	I_R	$V_{RWM} = 5.0\text{ V}$			0.1	μA
Clamping Voltage (Note 2)	V_C	$I_{PP} = 40\text{ A}, t_p = 8 \times 20\ \mu\text{s}$			7.5	V
Clamping Voltage (Note 2)	V_C	$I_{PP} = 80\text{ A}, t_p = 8 \times 20\ \mu\text{s}$			9.5	V
Clamping Voltage (Note 2)	V_C	$I_{PP} = 100\text{ A}, t_p = 8 \times 20\ \mu\text{s}$			10.5	V
Junction Capacitance	C_J	$V_R = 0\text{ V}, f = 1\text{ MHz}$			380	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- Breakdown voltage is tested from pin 1 to 2.
- Non-repetitive current pulse at $T_A = 25^\circ\text{C}$, per IEC61000-4-5 waveform, See Figure 10.

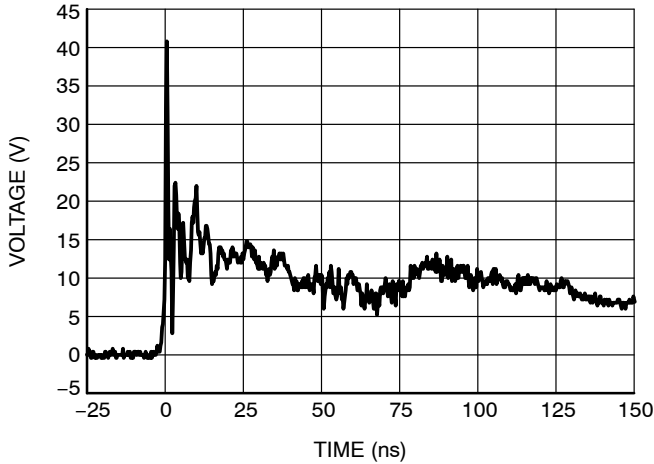


Figure 1. ESD Clamping Voltage Positive 8 kV Contact per IEC61000-4-2

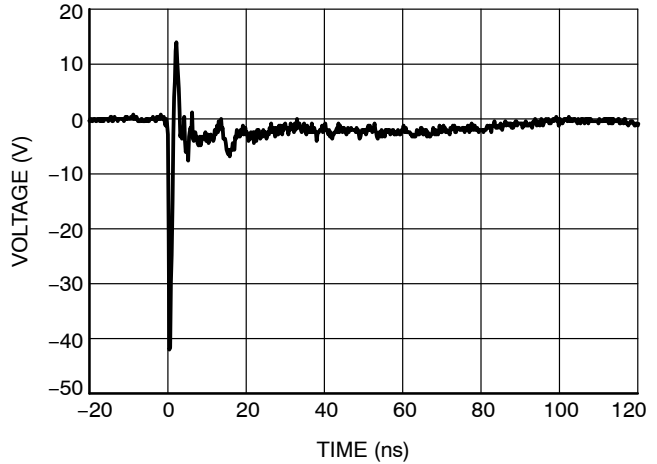


Figure 2. ESD Clamping Voltage Negative 8 kV Contact per IEC61000-4-2

NSPM2051

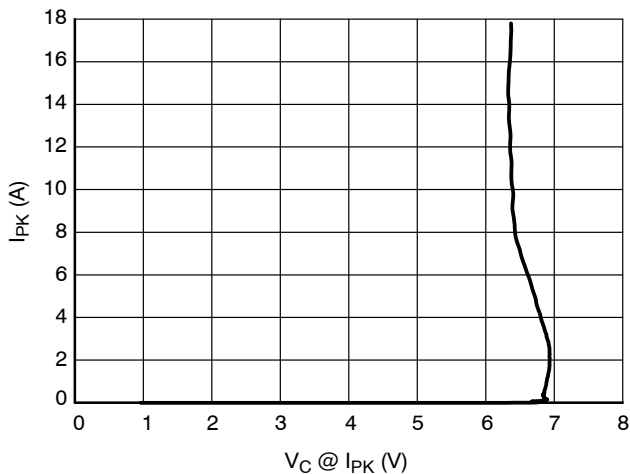


Figure 3. Positive TLP I-V Curve

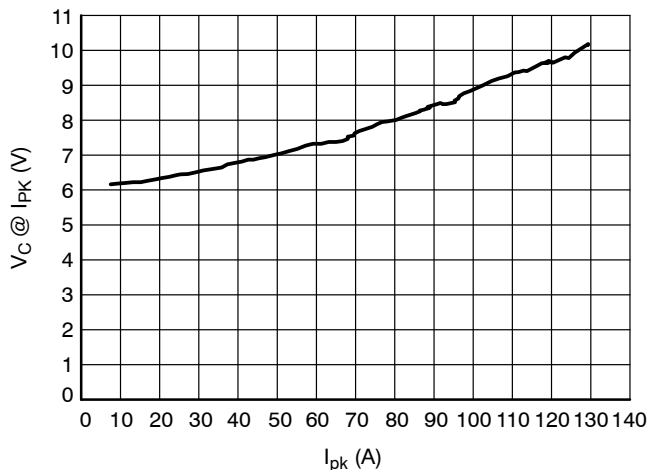


Figure 4. Clamping Voltage vs. Peak Pulse Current ($t_p = 8/20 \mu s$)

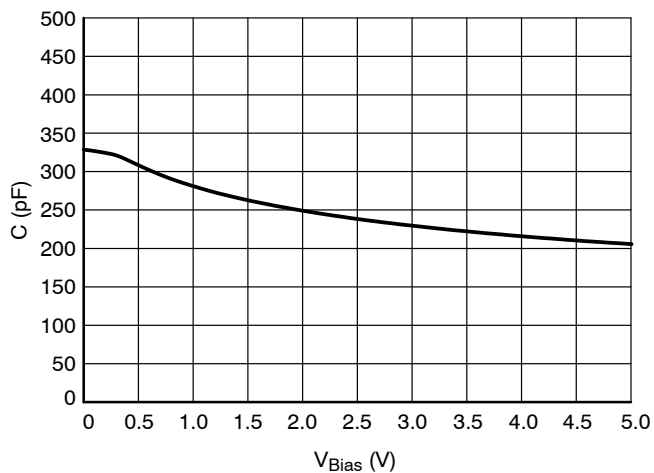


Figure 5. CV Characteristics

Transmission Line Pulse (TLP) Measurement

Transmission Line Pulse (TLP) provides current versus voltage (I-V) curves in which each data point is obtained from a 100 ns long rectangular pulse from a charged transmission line. A simplified schematic of a typical TLP system is shown in Figure 6. TLP I-V curves of ESD protection devices accurately demonstrate the product’s ESD capability because the 10s of amps current levels and under 100 ns time scale match those of an ESD event. This is illustrated in Figure 7 where an 8 kV IEC 61000-4-2 current waveform is compared with TLP current pulses at 8 A and 16 A. A TLP I-V curve shows the voltage at which the device turns on as well as how well the device clamps voltage over a range of current levels. For more information on TLP measurements and how to interpret them please refer to [AND9007/D](#).

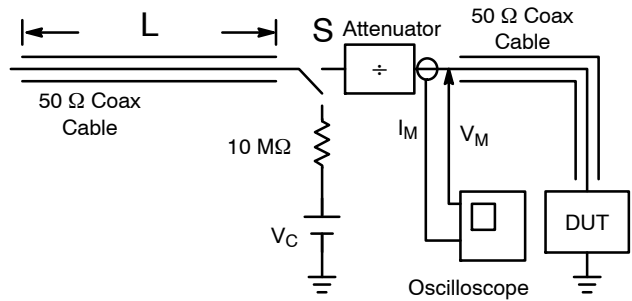


Figure 6. Simplified Schematic of a Typical TLP System

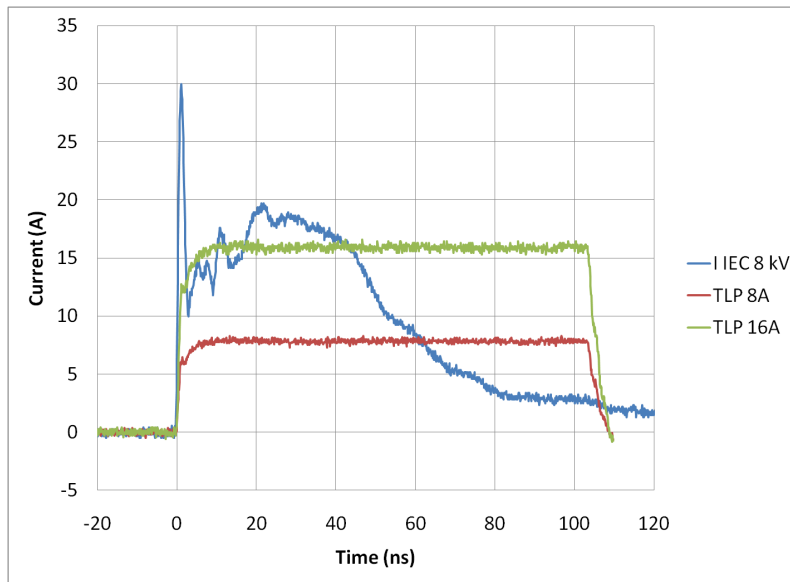


Figure 7. Comparison Between 8 kV IEC 61000-4-2 and 8 A and 16 A TLP Waveforms

IEC 61000-4-2 Spec.

Level	Test Voltage (kV)	First Peak Current (A)	Current at 30 ns (A)	Current at 60 ns (A)
1	2	7.5	4	2
2	4	15	8	4
3	6	22.5	12	6
4	8	30	16	8



Figure 8. IEC61000-4-2 Spec

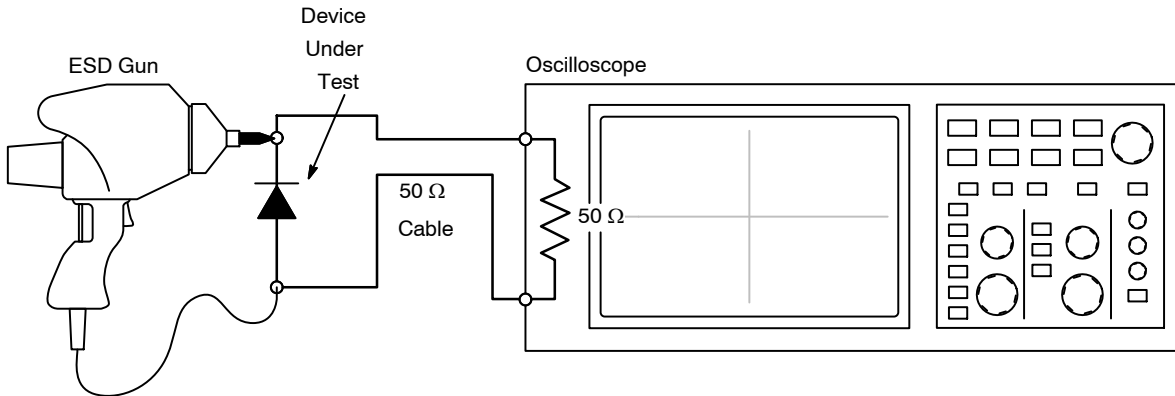


Figure 9. Diagram of ESD Test Setup

ESD Voltage Clamping

For sensitive circuit elements it is important to limit the voltage that an IC will be exposed to during an ESD event to as low a voltage as possible. The ESD clamping voltage is the voltage drop across the ESD protection diode during an ESD event per the IEC61000-4-2 waveform. Since the IEC61000-4-2 was written as a pass/fail spec for larger systems such as cell phones or laptop computers it is not

clearly defined in the spec how to specify a clamping voltage at the device level. **onsemi** has developed a way to examine the entire voltage waveform across the ESD protection diode over the time domain of an ESD pulse in the form of an oscilloscope screenshot, which can be found on the datasheets for all ESD protection diodes. For more information on how **onsemi** creates these screenshots and how to interpret them please refer to [AND8307/D](#).

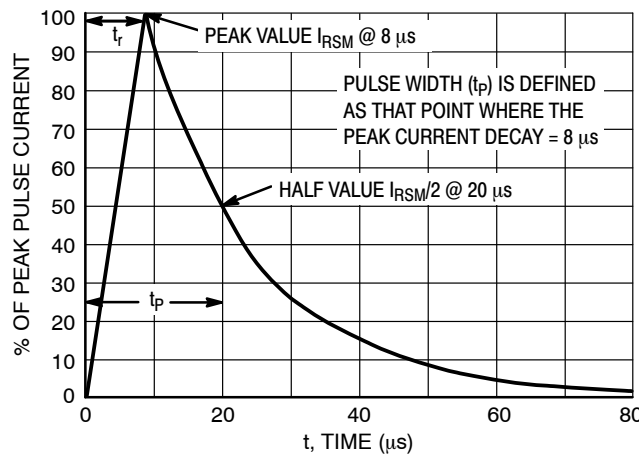


Figure 10. 8 x 20 μs Pulse Waveform

MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

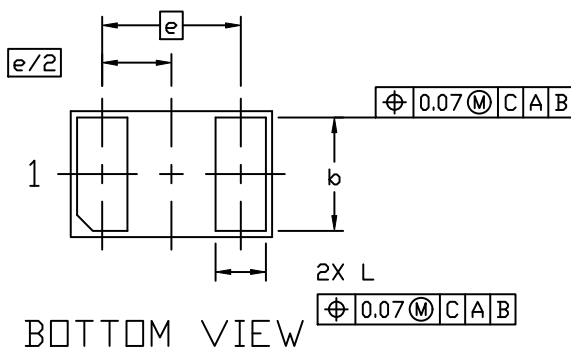
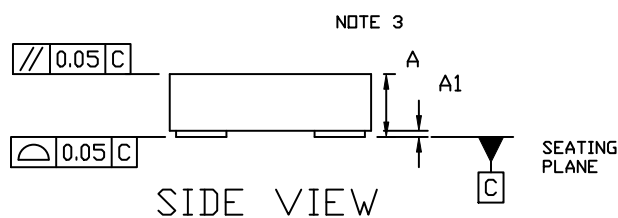
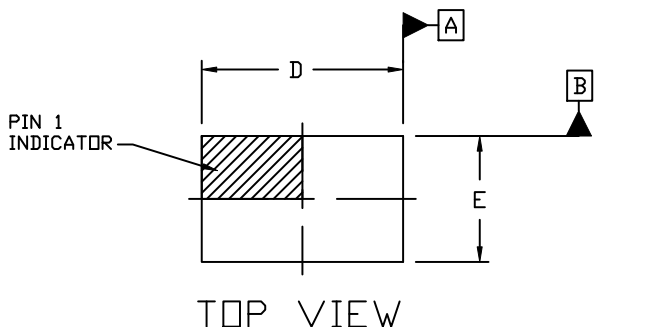
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SCALE 4:1

UDFN2 1.6x1.0, 1.1P
CASE 517CZ
ISSUE D

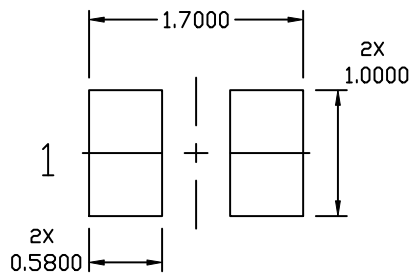
DATE 02 JUL 2020



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.45	0.50	0.55
A1	---	---	0.05
b	0.83	0.88	0.93
D	1.52	1.60	1.68
E	0.92	1.00	1.08
e	1.10 BSC		
L	0.35	0.40	0.45



* For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XX = Specific Device Code
M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G", may or not be present. Some products may not follow the Generic Marking.

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